

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%.

| Characteristic   | Symbol              | US1JDFQ | US1MDFQ | Unit |
|--|---------------------|---------|---------|------|
| Peak Repetitive Reverse Voltage                          | V <sub>RRM</sub>    |         |         |      |
| Working Peak Reverse Voltage                             | V <sub>RWM</sub>    | 600     | 1000    | V    |
| DC Blocking Voltage                                      | V <sub>R</sub>      |         |         |      |
| RMS Reverse Voltage                                      | V <sub>R(RMS)</sub> | 420     | 700     | V    |
| Average Rectified Output Current @T <sub>T</sub> = +25°C | I <sub>O</sub>      | 1.0     |         | A    |
| Non-Repetitive Peak Forward Surge Current 8.3ms          | I <sub>FSM</sub>    | 30      |         | A    |
| Single Half Sine-Wave Superimposed on Rated Load         |                     |         |         |      |

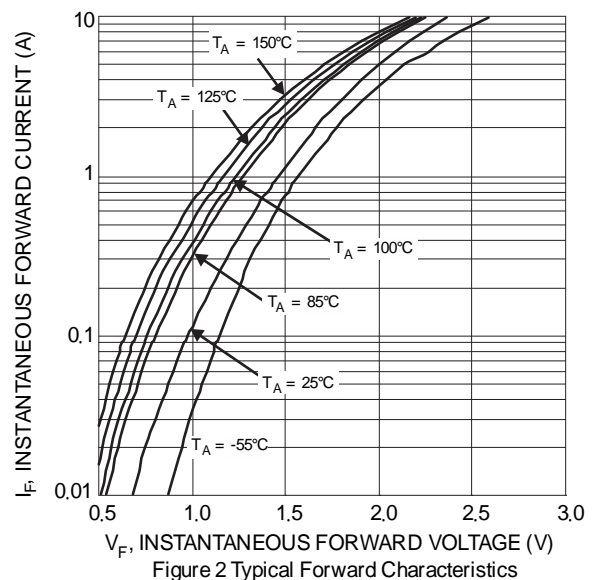
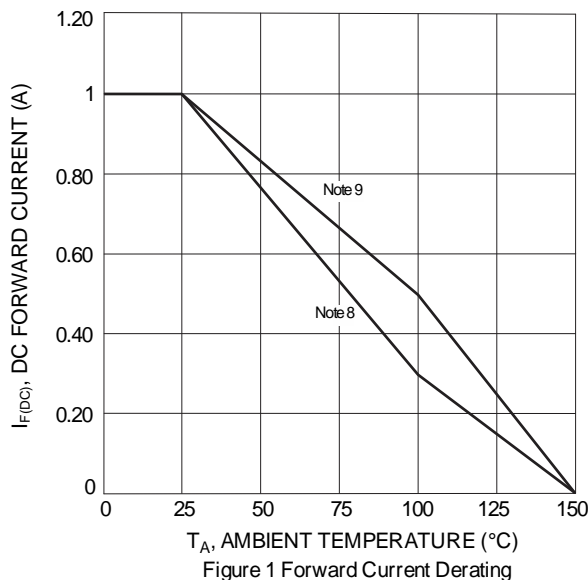
**Thermal Characteristics**

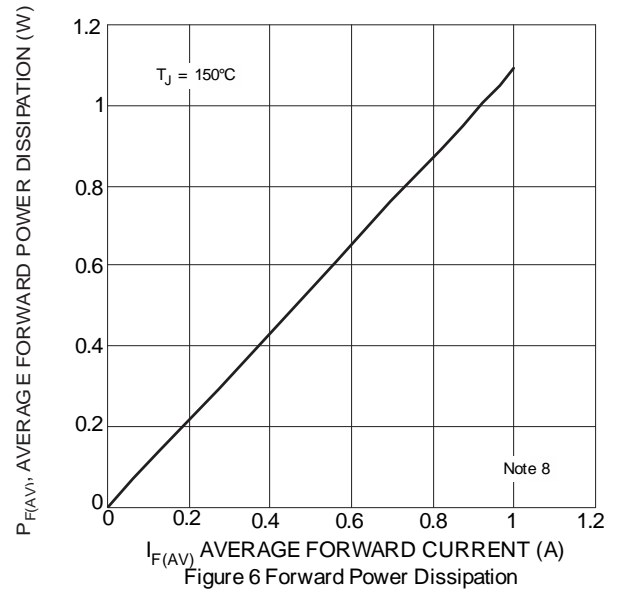
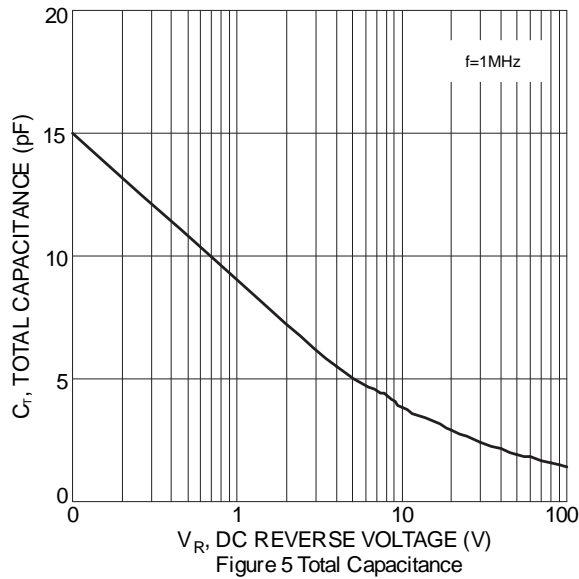
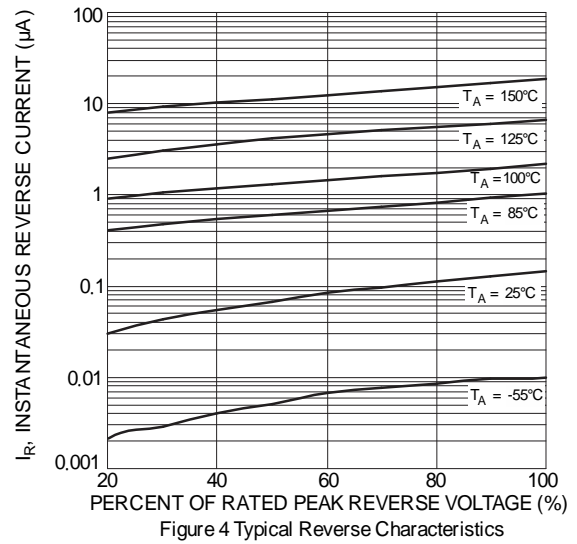
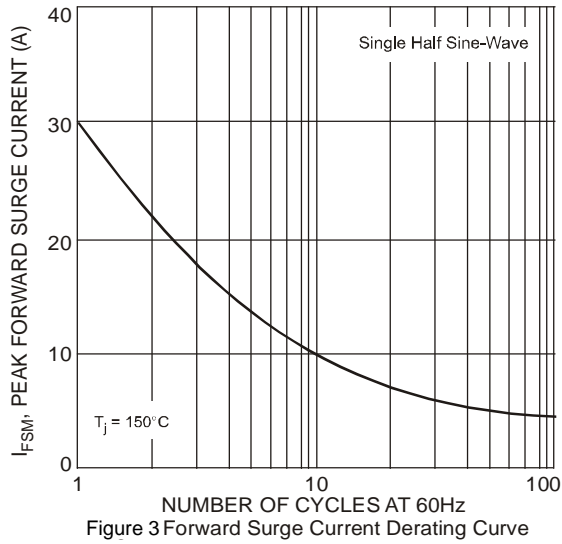
| Characteristic  | Symbol                            | Value       | Unit |
|---|-----------------------------------|-------------|------|
| Typical Thermal Resistance, Junction to Terminal (Note 8) | R <sub>θJT</sub>                  | 44          | °C/W |
| Typical Thermal Resistance, Junction to Ambient (Note 8)  | R <sub>θJA</sub>                  | 80          | °C/W |
| Operating and Storage Temperature Range                   | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 | °C   |

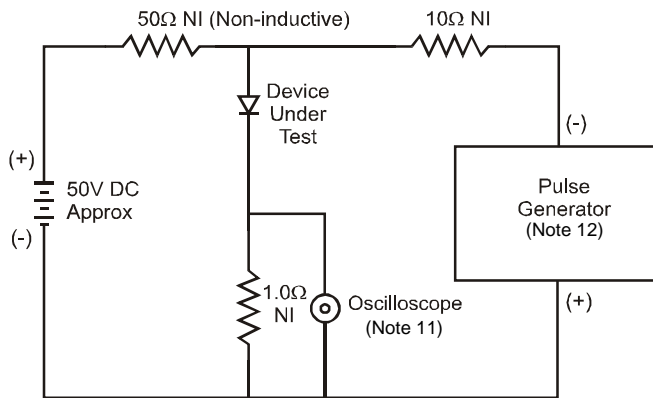
**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic   | Symbol             | US1JDFQ | US1MDFQ | Unit |
|--|--------------------|---------|---------|------|
| Minimum Reverse Breakdown Voltage (Note 6) @I <sub>R</sub> = 5μA | V <sub>(BR)R</sub> | 600     | 1000    | V    |
| Maximum Forward Voltage Drop @I <sub>F</sub> = 1.0A              | V <sub>F</sub>     | 1.7     |         | V    |
| Peak Reverse Current @T <sub>A</sub> = +25°C                     | I <sub>R</sub>     | 5.0     |         | μA   |
| at Rated DC Blocking Voltage (Note 6) @T <sub>A</sub> = +100°C   |                    | 100     |         |      |
| Maximum Reverse Recovery Time (Note 7)                           | t <sub>RR</sub>    | 75      |         | ns   |
| Typical Total Capacitance (Note 10)                              | C <sub>T</sub>     | 10      |         | pF   |

- Notes:
6. Short duration pulse test used to minimize self-heating effect.
  7. Measured with I<sub>F</sub> = 0.5A, I<sub>R</sub> = 1.0A, I<sub>RR</sub> = 0.25A. See Figure 7.
  8. Device mounted on FR-4 substrate, 1" \* 1", 2oz, single-sided, PC boards with 0.1" \* 0.15" copper pads.
  9. Device mounted on FR-4 substrate, 0.4" \* 0.5", 2oz, single-sided, PC boards with 0.2" \* 0.25" copper pads.
  10. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.



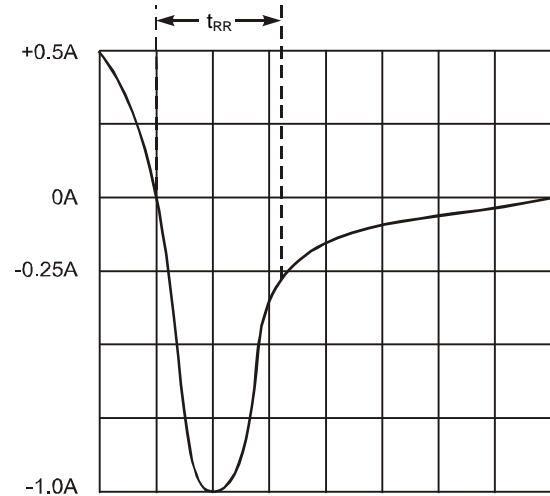




Notes:

11. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.

12. Rise Time = 10ns max. Input Impedance = 50Ω.



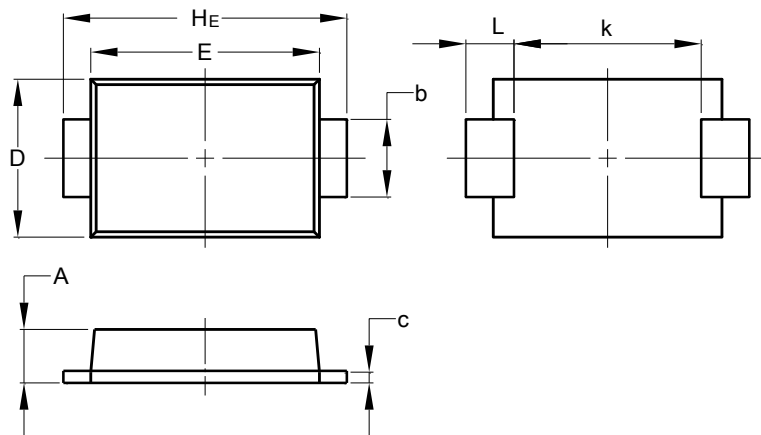
Set time base for 50/100 ns/cm

Figure 7 Reverse Recovery Time Characteristic and Test Circuit

## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### D-FLAT

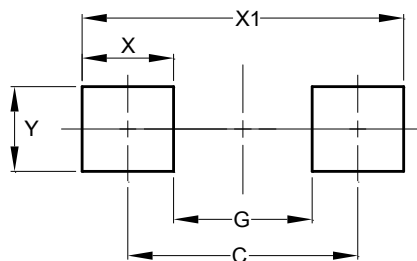


| D-FLAT               |      |      |
|----------------------|------|------|
| Dim                  | Min  | Max  |
| A                    | 0.90 | 1.10 |
| b                    | 1.25 | 1.65 |
| c                    | 0.10 | 0.40 |
| D                    | 2.25 | 2.95 |
| E                    | 3.95 | 4.60 |
| k                    | 2.80 | -    |
| HE                   | 5.00 | 5.60 |
| L                    | 0.50 | 1.30 |
| All Dimensions in mm |      |      |

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### D-FLAT



| Dimensions | Value (in mm) |
|------------|---------------|
| C          | 4.65          |
| G          | 2.80          |
| X          | 1.85          |
| X1         | 6.50          |
| Y          | 1.70          |

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